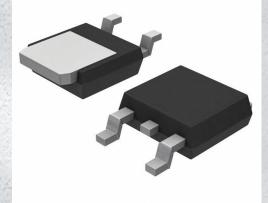


MJD210RLG Datasheet

www.digi-electronics.com



MID210RLG-DG
MJDZTOREG-DG
onsemi
MJD210RLG
TRANS PNP 25V 5A DPAK
Bipolar (BJT) Transistor PNP 25 V 5 A 65MHz 1.4 W S urface Mount DPAK

https://www.DiGi-Electronics.com



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MJD210RLG	onsemi
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	5 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
25 V	1.8V @ 1A, 5A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	45 @ 2A, 1V
Power - Max:	Frequency - Transition:
1.4 W	65MHz
Operating Temperature:	Mounting Type:
-65°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
ТО-252-3, DPAK (2 Leads + Tab), SC-63	DPAK
Base Product Number:	
MJD210	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	

Complementary Plastic Power Transistors

NPN/PNP Silicon DPAK For Surface Mount Applications

MJD200 (NPN), MJD210 (PNP)

Designed for low voltage, low-power, high-gain audio amplifier applications.

Features

- High DC Current Gain
- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Low Collector-Emitter Saturation Voltage
- High Current-Gain Bandwidth Product
- Annular Construction for Low Leakage
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector-Base Voltage	V _{CB}	40	Vdc
Collector-Emitter Voltage	V _{CEO}	25	Vdc
Emitter-Base Voltage	V_{EB}	8.0	Vdc
Collector Current – Continuous	Ι _C	5.0	Adc
Collector Current – Peak	I _{CM}	10	Adc
Base Current	Ι _Β	1.0	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	12.5 0.1	W W/°C
Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C	P _D	1.4 0.011	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C
ESD – Human Body Model	HBM	3B	V
ESD – Machine Model	MM	С	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

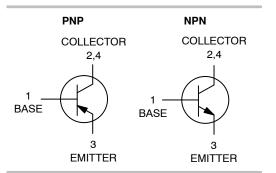
1. These ratings are applicable when surface mounted on the minimum pad sizes recommended.



ON Semiconductor®

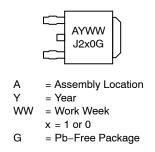
www.onsemi.com

SILICON POWER TRANSISTORS 5 AMPERES 25 VOLTS, 12.5 WATTS





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	10	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	89.3	°C/W

2. These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

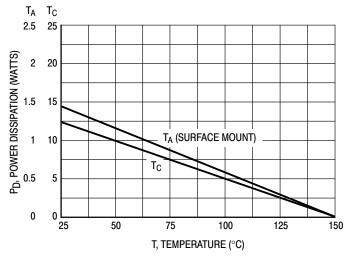
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	· · ·			
Collector-Emitter Sustaining Voltage (Note 3) $(I_C = 10 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	25	_	Vdc
Collector Cutoff Current (V_{CB} = 40 Vdc, I_E = 0) (V_{CB} = 40 Vdc, I_E = 0, T_J = 125°C)	I _{CBO}		100 100	nAdc μAdc
Emitter Cutoff Current ($V_{BE} = 8$ Vdc, $I_C = 0$)	I _{EBO}	_	100	nAdc
ON CHARACTERISTICS				
C Current Gain (Note 3), ($I_C = 500 \text{ mAdc}, V_{CE} = 1 \text{ Vdc}$) ($I_C = 2 \text{ Adc}, V_{CE} = 1 \text{ Vdc}$) ($I_C = 5 \text{ Adc}, V_{CE} = 2 \text{ Vdc}$)	h _{FE}	70 45 10	- 180 -	-
Collector-Emitter Saturation Voltage (Note 3) ($I_C = 500 \text{ mAdc}$, $I_B = 50 \text{ mAdc}$) ($I_C = 2 \text{ Adc}$, $I_B = 200 \text{ mAdc}$) ($I_C = 5 \text{ Adc}$, $I_B = 1 \text{ Adc}$)	V _{CE(sat)}	- - -	0.3 0.75 1.8	Vdc
Base-Emitter Saturation Voltage (Note 3) ($I_C = 5 \text{ Adc}, I_B = 1 \text{ Adc}$)	V _{BE(sat)}	_	2.5	Vdc
Base-Emitter On Voltage (Note 3) (I _C = 2 Adc, V _{CE} = 1 Vdc)	V _{BE(on)}		1.6	Vdc

DYNAMIC CHARACTERISTICS

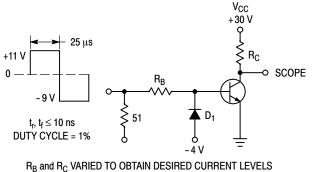
Current–Gain – Bandwidth Product (Note 4) (I _C = 100 mAdc, V _{CE} = 10 Vdc, f _{test} = 10 MHz)	f _T	65	_	MHz
Output Capacitance ($V_{CB} = 10$ Vdc, $I_E = 0$, f = 0.1 MHz) MJD200 MJD210, NJVMJD210T4G	C _{ob}		80 120	pF

3. Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle \approx 2%.

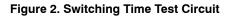
4. $f_T = |h_{fe}| \bullet f_{test}$.







FOR PNP TEST CIRCUIT, REVERSE ALL POLARITIES



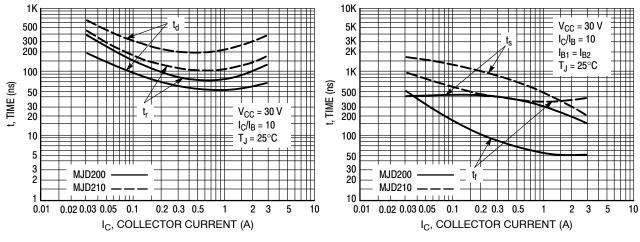
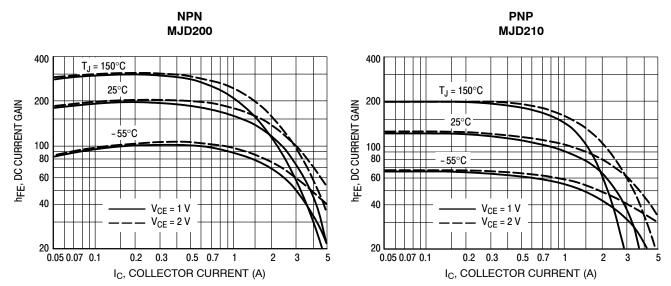
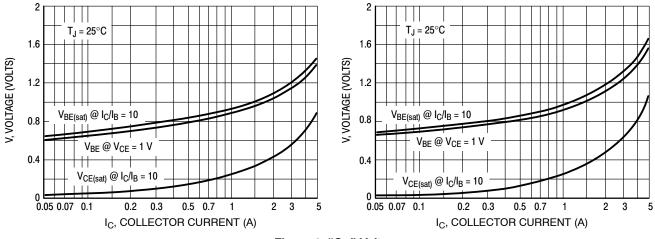


Figure 3. Turn-On Time

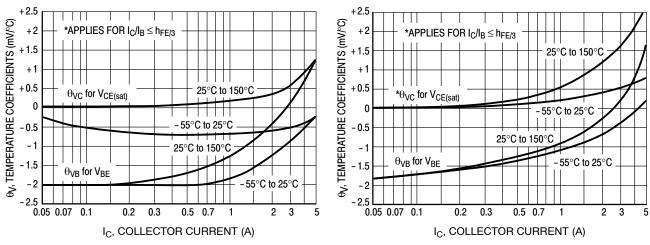
Figure 4. Turn-Off Time

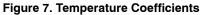












MJD200 (NPN), MJD210 (PNP)

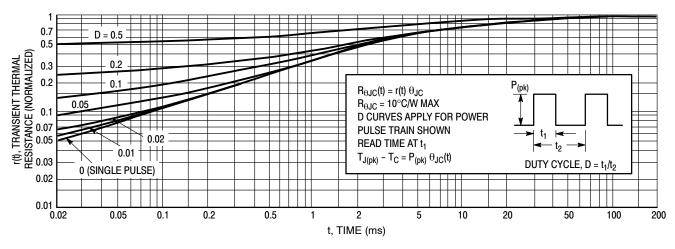


Figure 8. Thermal Response

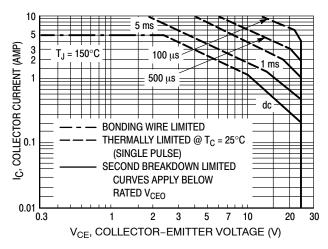


Figure 9. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 9 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

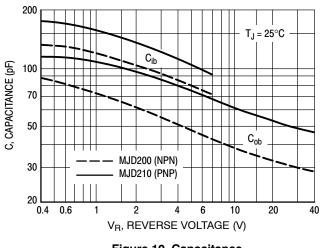


Figure 10. Capacitance

ORDERING INFORMATION

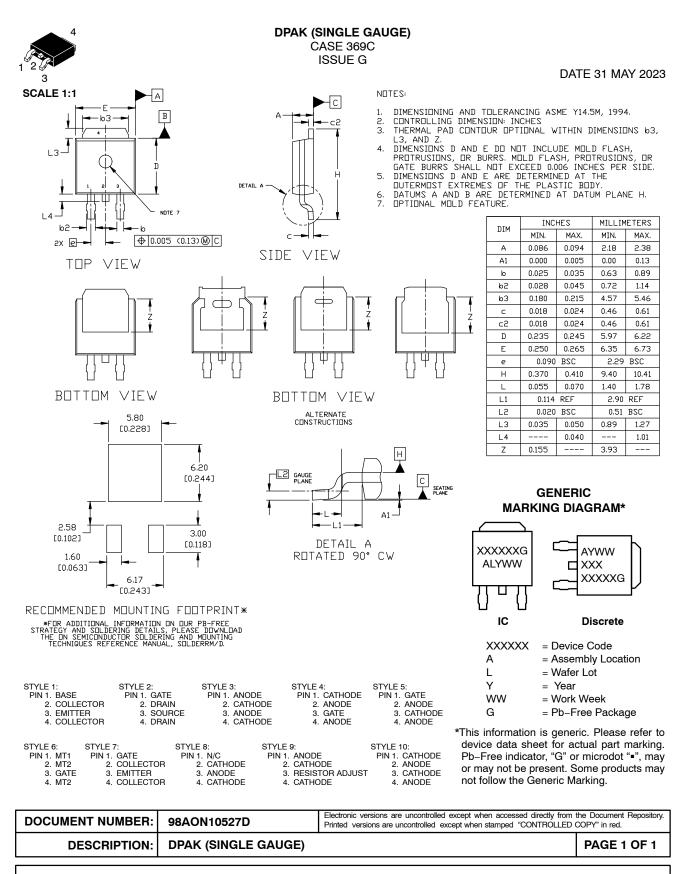
Device	Package Type	Shipping [†]
MJD200G	DPAK (Pb-Free)	75 Units / Rail
MJD200RLG	DPAK (Pb-Free)	1,800 / Tape & Reel
MJD200T4G	DPAK (Pb-Free)	2,500 / Tape & Reel
MJD210G	DPAK (Pb-Free)	75 Units / Rail
MJD210RLG	DPAK (Pb–Free)	1,800 / Tape & Reel
MJD210T4G	DPAK (Pb-Free)	2,500 / Tape & Reel
NJVMJD210T4G*	DPAK (Pb-Free)	2,500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable



PACKAGE DIMENSIONS



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